

Photologic™ Slotted Optical Switches

Types OPB980, OPB990 Series



Features

- Choice of mounting configuration
- Choice of aperture
- Choice of output configuration
- Choice of opaque or IR transmissive shell material
- Data rates to 250 kBaud
- 24" min 26AWG wire leads

Description

The OPB980 and OPB990 series of Photologic™ Photo Integrated Circuit Switches provide optimum flexibility for the design engineer. Building from a standard housing with a .125" wide slot, the user can specify (1) type and polarity of TTL output, (2) discrete shell material, (3) aperture width, and (4) choice of mounting configuration.

The electrical output can be satisfied as either TTL totem pole or TTL open collector. Either may be supplied with inverter or buffer output polarity. All have added stability of a built-in hysteresis amplifier.

Absolute Maximum Ratings ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Supply Voltage, V_{CC} (Not to exceed 3 sec.)	10V
Storage Temperature Range	-40°C to $+80^\circ\text{C}$
Operating Temperature Range	-40°C to $+70^\circ\text{C}$
Input Diode Power Dissipation	100mW ⁽¹⁾
Output Photologic™ Power Dissipation	200mW ⁽²⁾
Total Device Power Dissipation	300mW ⁽³⁾
Voltage at Output Lead (Open Collector Output)	35V
Diode Forward D.C. Current	40mA
Diode Reverse D.C. Voltage	2V

Notes:

- (1) Derate linearly 2.22mW/ $^\circ\text{C}$ above 25°C .
- (2) Derate linearly 4.44mW/ $^\circ\text{C}$ above 25°C .
- (3) Derate linearly 6.66mW/ $^\circ\text{C}$ above 25°C .
- (4) The OPB980/OPB990 series of switches are terminated with 24 inches of 7 strand 26 AWG, UL 1429 insulated wire on each terminal. Insulation colors and functions are:

RED - IRED Anode	WHITE - V_{CC}
BLACK - IRED Cathode	BLUE - Output
	GREEN - Ground

Other wire lengths and/or colors in addition to customer selected connectors are available. Contact your local representative or call the factory.

- (5) Normal application would be with light source blocked, simulated by $I_F = 0\text{mA}$.
- (6) All parameters tested using pulse techniques.

Housing

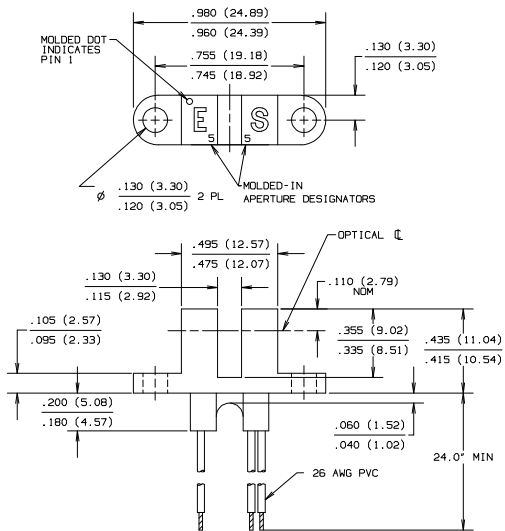
All housings are an opaque grade of injection-molded plastic to minimize the assembly's sensitivity to ambient radiation, both visible and near-infrared. Discrete shells (exposed on the parallel faces inside the device throat) are either IR transmissive plastic for applications where aperture contamination may occur or opaque plastic for maximum protection against ambient light.

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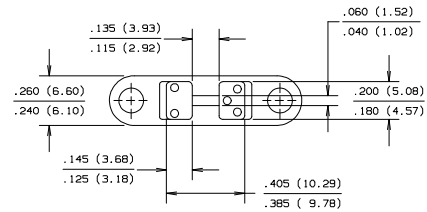
Electrical Characteristics ($T_A = -40^{\circ}\text{C}$ to $+70^{\circ}\text{C}$ unless otherwise noted).

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Input Diode						
V_F	Forward Voltage			1.7	V	$I_F = 20\text{ mA}$, $T_A = 25^{\circ}\text{C}$
I_R	Reverse Current			100	μA	$V_R = 2.0\text{ V}$, $T_A = 25^{\circ}\text{C}$
Output Photologic[®] Sensor						
V_{CC}	Operating D.C. Supply Voltage	4.75		5.25	V	
I_{CCL}	Low Level Supply Current: Buffered Totem-Pole Output Buffered Open-Collector Output			15	mA	$V_{CC} = 5.25\text{ V}$, $I_F = 0\text{ mA}^{(5)}$
	Inverted Totem-Pole Output Inverted Open-Collector Output			15	mA	$V_{CC} = 5.25\text{ V}$, $I_F = 15\text{ mA}$
I_{CCH}	High Level Supply Current: Buffered Totem-Pole Output Buffered Open-Collector Output			15	mA	$V_{CC} = 5.25\text{ V}$, $I_F = 15\text{ mA}$
	Inverted Totem-Pole Output Inverted Open-Collector Output			15	mA	$V_{CC} = 5.25\text{ V}$, $I_F = 0\text{ mA}^{(5)}$
V_{OL}	Low Level Output Voltage: Buffered Totem-Pole Output Buffered Open-Collector Output			0.4	V	$V_{CC} = 4.75\text{ V}$, $I_{OL} = 12.8\text{ mA}$ $I_F = 0\text{ mA}^{(5)}$
	Inverted Totem-Pole Output Inverted Open-Collector Output			0.4	V	$V_{CC} = 4.75\text{ V}$, $I_{OL} = 12.8\text{ mA}$ $I_F = 15\text{ mA}$
V_{OH}	High Level Output Voltage: Buffered Totem-Pole Output	2.4			V	$V_{CC} = 4.75\text{ V}$, $I_{OH} = -800\text{ }\mu\text{A}$ $I_F = 15\text{ mA}$
	Inverted Totem-Pole Output	2.4			V	$V_{CC} = 4.75\text{ V}$, $I_{OH} = -800\text{ }\mu\text{A}$ $I_F = 0\text{ mA}^{(5)}$
I_{OH}	High Level Output Current: Buffered Open-Collector Output			100	μA	$V_{CC} = 4.75\text{ V}$, $V_{OH} = 30\text{ V}$, $I_F = 15\text{ mA}$, $T_A = 25^{\circ}\text{C}$
	Inverted Open-Collector Output			100	μA	$V_{CC} = 4.75\text{ V}$, $V_{OH} = 30\text{ V}$, $I_F = 0\text{ mA}$, $T_A = 25^{\circ}\text{C}$
$I_F(+)$	LED Positive-Going Threshold Current			15	mA	$V_{CC} = 5.0\text{ V}$, $T_A = 25^{\circ}\text{C}$
$I_F(+)/I_F(-)$	Hysteresis		2.0			$V_{CC} = 5.0\text{ V}$
I_{OS}	Short Circuit Output Current: Buffered Totem-Pole Output "11" Series	-15		-60	mA	$V_{CC} = 5.25\text{ V}$, $I_F = 15\text{ mA}$ Output = GND
	Inverted Totem-Pole Output "11" Series	-30		-60	mA	$V_{CC} = 5.25$, $I_F = 0\text{ mA}$ Output = GND

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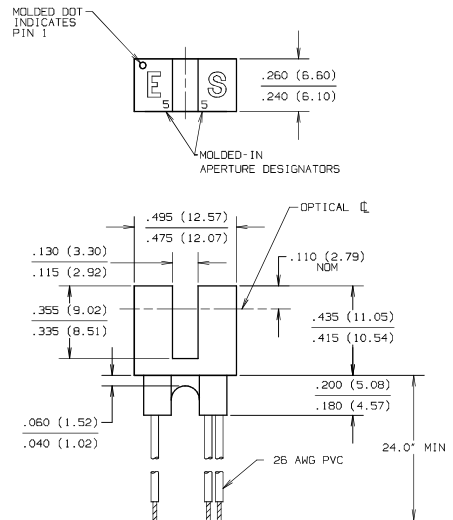


DIMENSIONS ARE IN INCHES (MILLIMETERS)

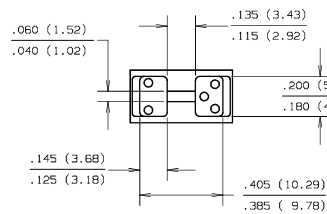


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Package N

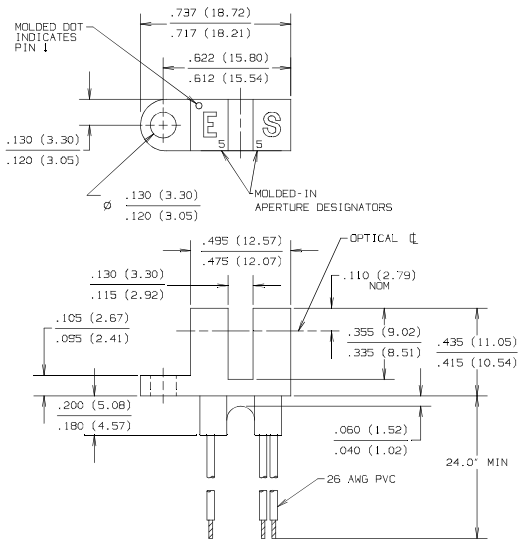


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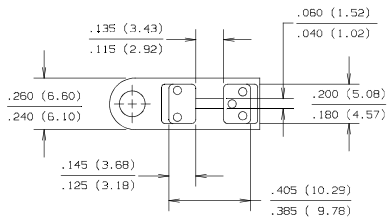


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Package L

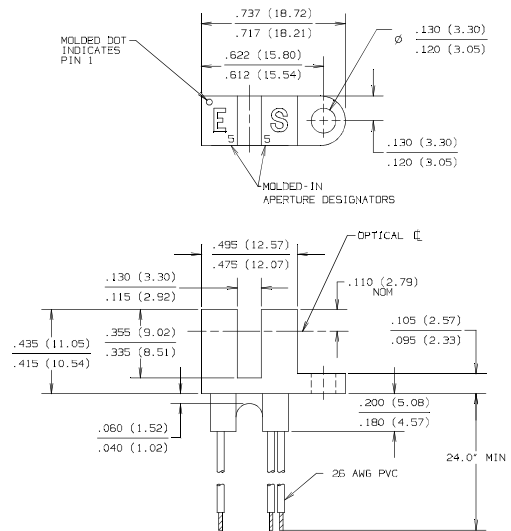


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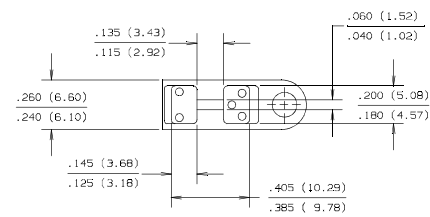


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Package P



DIMENSIONS ARE IN INCHES (MILLIMETERS)



DIMENSIONS ARE IN INCHES (MILLIMETERS)

PART NUMBER GUIDE

OPB 9 X X X X X

Optek Assembly		Aperture Width In Front of Sensor 5 = 0.050" 1= 0.010"
Photologic™ Photo Integrated Circuit Sensor Family		Aperture Width In Front of Emitter 5 = 0.050" 1= 0.010"
Discrete Shell Material Designation		Mounting Configurations
8 - Base Mount IR Transmissive Plastic Discrete Shell With Wire Termination		T - Both Mounting Tabs N - No Mounting Tabs L - Single Mounting Tab Emitter Side
9 - Base Mount Opaque Plastic Discrete Shell With Wire Termination		P - Single Mounting Tab Photologic™ Side

Electrical Specification Variations

- 0 - Buffered Totem-Pole Output
- 1 - Buffered Open-Collector Output
- 2 - Inverted Totem-Pole Output
- 3 - Inverted Open-Collector Output

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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